

## 2SK2960

## Silicon N-Channel Power F-MOS FET

## ■ Features

- Avalanche energy capacity guaranteed: EAS > 250mJ
- $V_{GSS} = \pm 30V$  guaranteed
- High-speed switching:  $t_f = 55ns$
- No secondary breakdown

## ■ Applications

- Contactless relay
- Diving circuit for a solenoid
- Driving circuit for a motor
- Control equipment
- Switching power supply

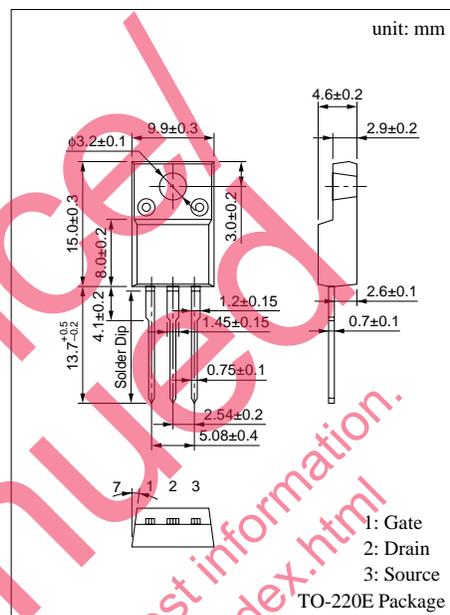
■ Absolute Maximum Ratings ( $T_C = 25^\circ C$ )

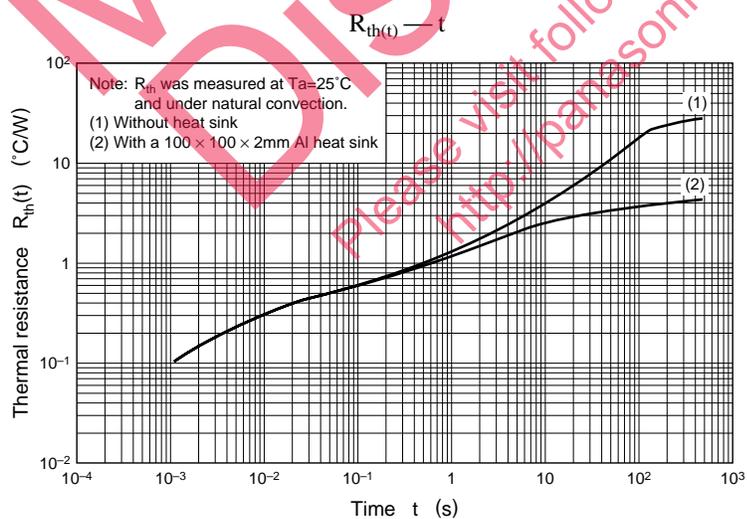
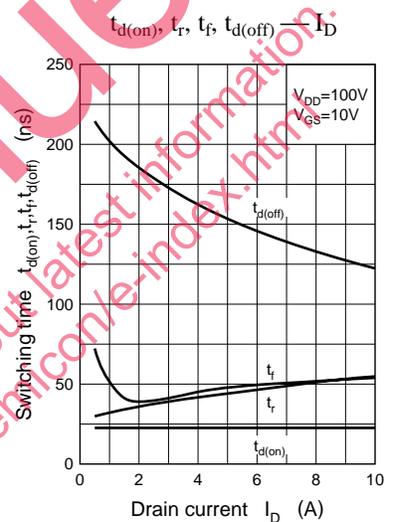
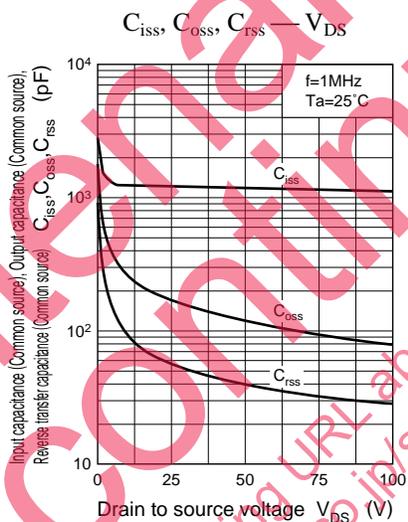
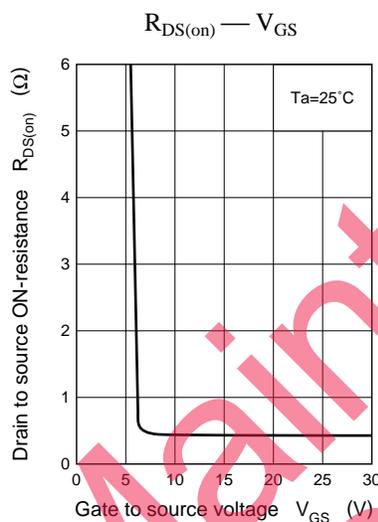
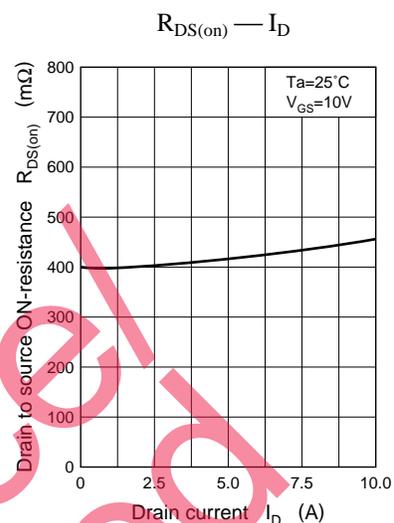
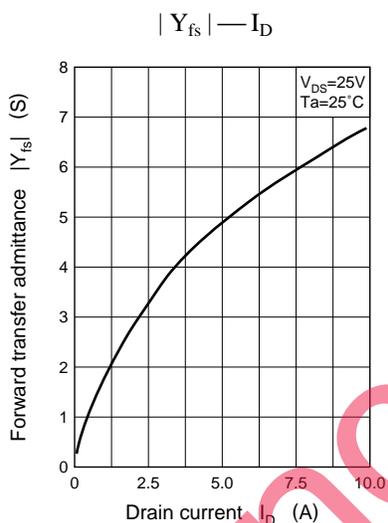
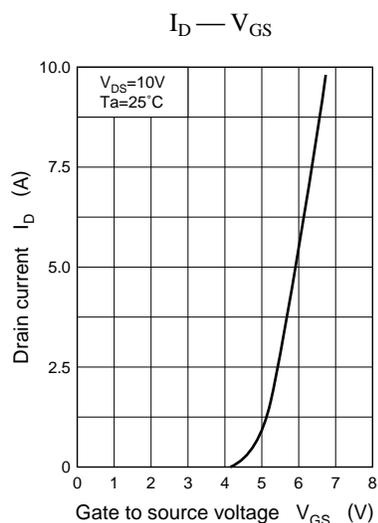
Parameter	Symbol	Rated	Unit
Drain to Source breakdown voltage	$V_{DSS}$	400	V
Gate to Source voltage	$V_{GSS}$	$\pm 30$	V
Drain current	DC	$I_D$	$\pm 10$ A
	Pulse	$I_{DP}$	$\pm 20$ A
Avalanche energy capacity	EAS*	250	mJ
Allowable power dissipation	$T_C = 25^\circ C$	$P_D$	50 W
	$T_a = 25^\circ C$		2
Channel temperature	$T_{ch}$	150	$^\circ C$
Storage temperature	$T_{stg}$	-55 to +150	$^\circ C$

\*  $L = 5mH$ ,  $I_L = 10A$ , 1 pulse

■ Electrical Characteristics ( $T_C = 25^\circ C$ )

Parameter	Symbol	Conditions	min	typ	max	Unit
Drain to Source cut-off current	$I_{DSS}$	$V_{DS} = 320V$ , $V_{GS} = 0$			0.1	mA
Gate to Source leakage current	$I_{GSS}$	$V_{GS} = \pm 30V$ , $V_{DS} = 0$			$\pm 1$	$\mu A$
Drain to Source breakdown voltage	$V_{DSS}$	$I_D = 1mA$ , $V_{GS} = 0$	400			V
Gate threshold voltage	$V_{th}$	$V_{DS} = 10V$ , $I_D = 1mA$	2		5	V
Drain to Source ON-resistance	$R_{DS(on)}$	$V_{GS} = 10V$ , $I_D = 5A$		0.4	0.52	$\Omega$
Forward transfer admittance	$ Y_{fs} $	$V_{DS} = 10V$ , $I_D = 5A$	3	5		S
Diode forward voltage	$V_{DSF}$	$I_{DR} = 10A$ , $V_{GS} = 0$			-1.5	V
Input capacitance (Common Source)	$C_{iss}$	$V_{DS} = 10V$ , $V_{GS} = 0$ , $f = 1MHz$		1400		pF
Output capacitance (Common Source)	$C_{oss}$			290		pF
Reverse transfer capacitance (Common Source)	$C_{rss}$			100		pF
Turn-on time (delay time)	$t_{d(on)}$				25	
Rise time	$t_r$	$V_{GS} = 10V$ , $I_D = 5A$		50		ns
Turn-off time (delay time)	$t_{d(off)}$	$V_{DD} = 100V$ , $R_L = 20\Omega$		170		ns
Fall time	$t_f$			55		ns





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